TECHSEM

Y100ZPE
RECTIFIER DIODE

Features

- Low forward voltage drop
- High reverse voltage
- Hermetic metal cases with ceramic insulators

Typical Applications

- All purpose high power rectifier diodes
- High power resistance welding equipment
- Non-controllable and half-controllable rectifiers
- Controlled rectifiers

$I_{F(AV)}$	**6490A**
V_{RRM}	**3100~4200 V**
I_{FSM}	**80 kA**
I^2t	**32000 10^3A^2S**

SYMBOL	CHARACTERISTIC	TEST CONDITIONS		T_j(°C)	VALUE			UNIT
					Min	Type	Max	
$I_{F(AV)}$	Mean forward current	180° half sine wave 50Hz Double side cooled,	T_C=85°C	160			6490	A
V_{RRM}	Repetitive peak reverse voltage	tp=10ms		160	3100		4200	V
I_{RRM}	Repetitive peak current	At V_{RRM}		160			250	mA
I_{FSM}	Surge forward current	10ms half sine wave V_R=0.6V_{RRM}		160			80	kA
I^2t	I^2t for fusing coordination						32000	A^2s*10^3
V_{FO}	Threshold voltage			160			0.92	V
r_F	Forward slope resistance						0.087	mΩ
V_{FM}	Peak forward voltage	I_{FM}=5000A, F=90kN		25			1.75	V
Q_{rr}	Recovery charge	I_{FM}=2000A,tp=2000μs, di/dt=-20A/μs, V_R=50V		160		9000		μC
$R_{th(j-c)}$	Thermal resistance Junction to case	At 180^0 sine, double side cooled Clamping force 90kN					0.005	°C /W
$R_{th(c-h)}$	Thermal resistance case to heat sink						0.0015	
F_m	Mounting force				81		108	kN
T_{stg}	Stored temperature				-40		160	°C
W_t	Weight					2000		g
Outline	ZT100cT							

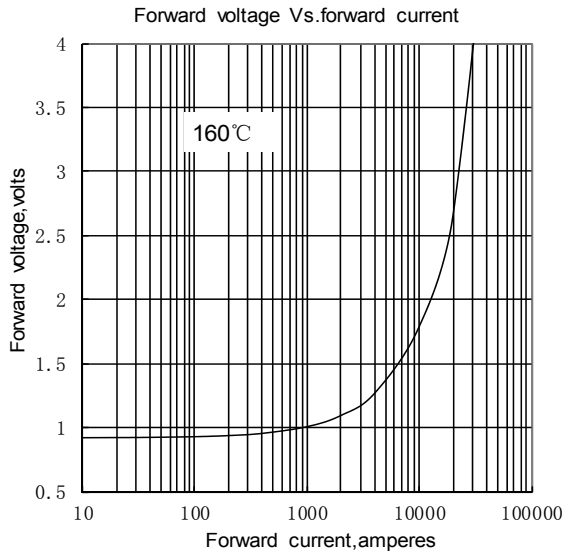

Fig.1

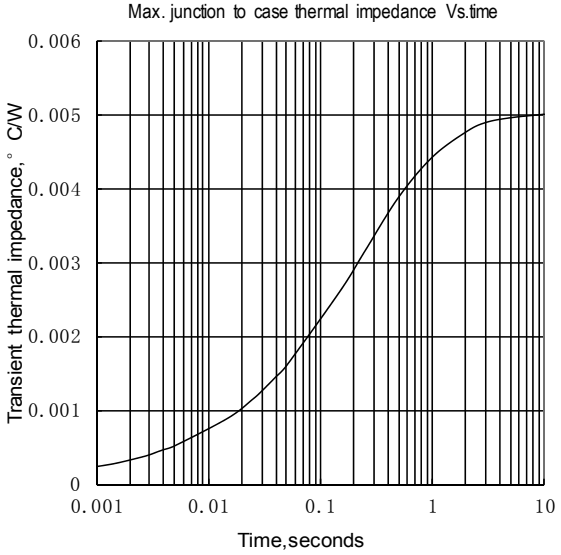

Fig.2

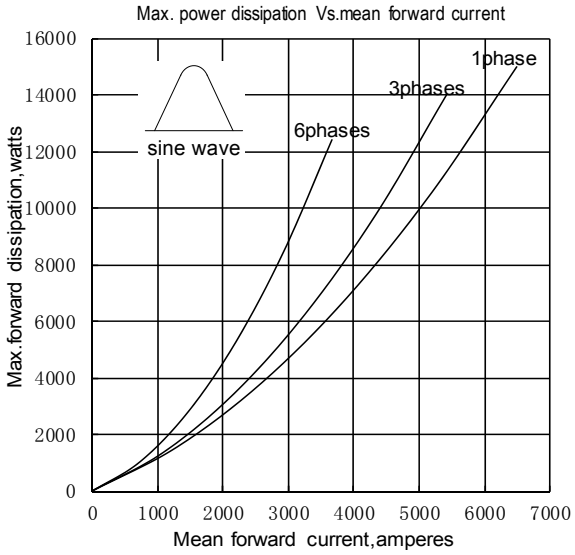

Fig.3

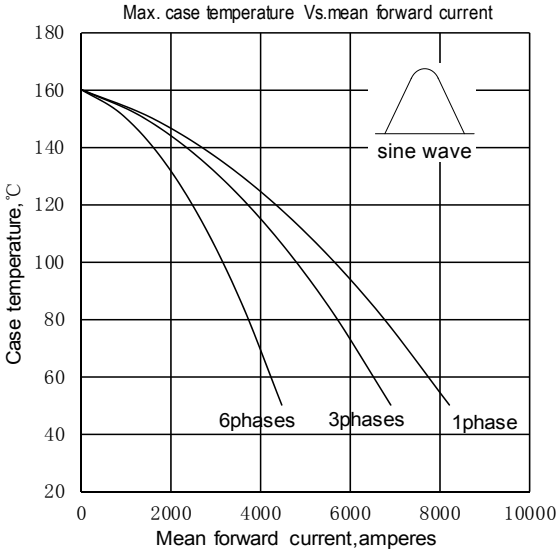

Fig.4

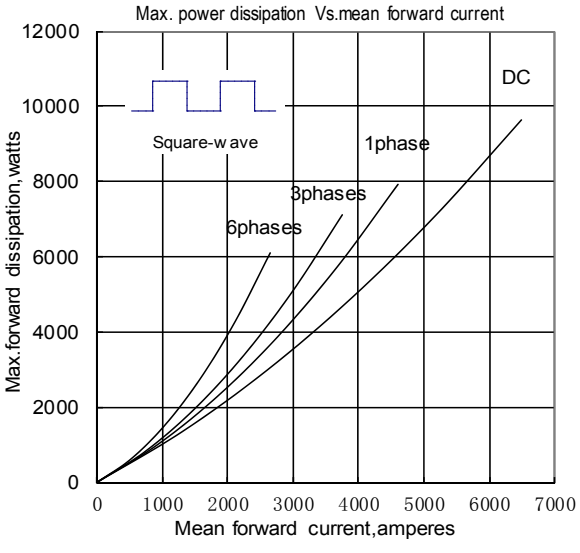

Fig.5

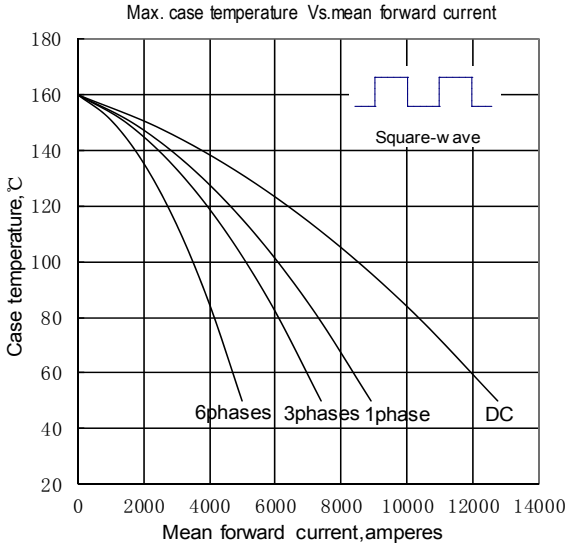

Fig.6

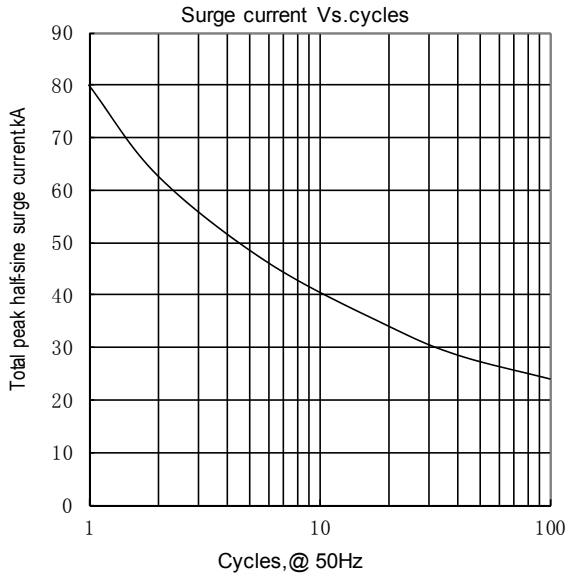

Fig.7

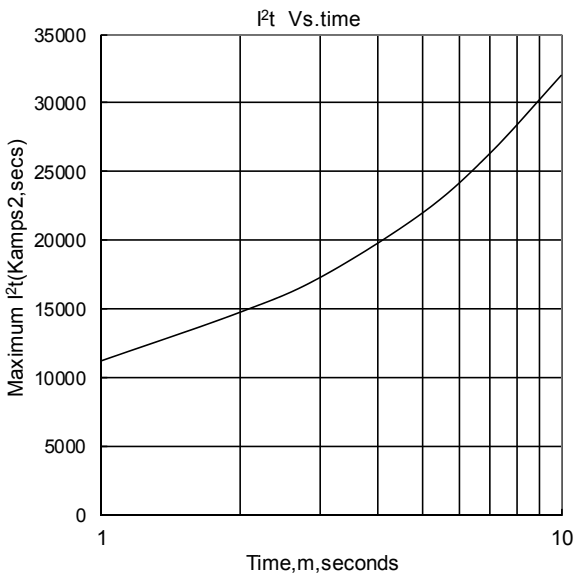

Fig.8

Outline: